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MC68L11L6

Supplement to Technical Data

Low Voltage Devices

The MC68L11L6 is an extended-voltage version of the MC68HC11L6 microcontroller that can operate in applications that require supply voltages as low as 3.0 Volts. Operation of the MC68L11L6 is identical to that of the MC68HC11L6 in all aspects other than electrical parameters.

This document provides MC68L11L6 electrical characteristics. It is a supplement to Appendix A of the MC68HC11L6 Technical Data (MC68HC11L6/D). Refer to the data book for technical information regarding use and operation of the microcontroller. The extended-range electrical characteristics in this supplement will be incorporated into the data book in a subsequent revision.

Features

- Suitable for Battery-Powered Portable and Hand-Held Applications
- · Excellent for use in Applications such as Remote Sensors and Actuators
- · Reduced RF Noise
- Operating Performance is Same at 5V and 3V

Ordering Information

Package	Temperature	Frequency	Features	MC Order Number
68-Pin PLCC	0° to + 70° C	2 MHz	Custom ROM	MC68L11L6FN2
			Custom ROM, No EEPROM	MC68L11L5FN2
			No ROM	MC68L11L1FN2
			No ROM, No EEPROM	MC68L11L0FN2
64-Pin QFP	0° to + 70° C	2 MHz	Custom ROM	MC68L11L6FU2
			Custom ROM, No EEPROM	MC68L11L5FU2
			No ROM	MC68L11L1FU2
			No ROM, No EEPROM	MC68L11L0FU2





SUPPLEMENT TO APPENDIX A ELECTRICAL CHARACTERISTICS: LOW VOLTAGE DEVICES

Table A-1a. Maximum Ratings

Rating	Symbol	Value	Unit
Supply Voltage	V _{DD}	- 0.3 to + 7.0	٧
Input Voltage	V _{in}	- 0.3 to + 7.0	V
Operating Temperature Range MC68L11L6	T _A	T _L to T _H -20 to +70	°C
Storage Temperature Range	T _{stg}	- 55 to + 150	℃
Current Drain per Pin* Excluding V _{DD} , V _{SS} , AV _{DD} , V _{RH} , and V _{RL}	I _D	25	mA

^{*}One pin at a time, observing maximum power dissipation limits.

Internal circuitry protects the inputs against damage caused by high static voltages or electric fields; however, normal precautions are necessary to avoid application of any voltage higher than maximum-rated voltages to this high-impedance circuit. Extended operation at the maximum ratings can adversely affect device reliability. Tying unused inputs to an appropriate logic voltage level (either GND or V_{DD}) enhances reliability of operation.

Table A-2a. Thermal Characteristics

Characteristic		Symbol	Value	Unit
Average Junction Temperature		Tj	$T_A + (P_D \times \Theta_{JA})$	℃
Ambient Temperature		T _A	User-determined	℃
Package Thermal Resistance (Junction-to-Ambi 68-Pin Plastic Leaded Chip Carrier (PLCC) 64-Pin Quad Flat Pack (QFP)	ent)	ӨЈА	50 85	°C/W
Total Power Dissipation (N	lote 1)	P _D	P _{INT} + P _{I/O} K / (T _J + 273°C)	W
Device Internal Power Dissipation		PINT	I _{DD} x V _{DD}	w
I/O Pin Power Dissipation (Note 2)		P _{I/O}	User-determined	W
A Constant (N	lote 3)	К	P _D x (T _A + 273°C) + Θ _{JA} x P _D ²	W⋅⋅C

NOTES:

- 1. This is an approximate value, neglecting P_{I/O}.
- 2. For most applications P_{I/O} « P_{INT} and can be neglected.
- 3. K is a constant pertaining to the device. Solve for K with a known T_A and a measured P_D (at equilibrium). Use this value of K to solve for P_D and T_J iteratively for any value of T_A .



Table A-3a. DC Electrical Characteristics

 V_{DD} = 3.0 Vdc to 5.5 Vdc, V_{SS} = 0 Vdc, T_A = T_L to T_H , unless otherwise noted

Characteristic	Symbol	Min	Max	Unit
Output Voltage (Note 1) All Outputs except XTAL All Outputs Except XTAL, RESET, and MODA ILoad = ± 10.0 µA	V _{OL} V _{OH}	 V _{DD} - 0.1	0.1 —	V V
Output High Voltage (Note 1) All Outputs Except XTAL, RESET, and MODA I _{Load} = -0.5mA, V _{DD} = 3.0 V I _{Load} = -0.8 mA, V _{DD} = 4.5 V	Voн	V _{DD} - 0.8	_	V
Output Low Voltage All Outputs Except XTAL $I_{Load} = 1.6$ mA, $V_{DD} = 5.0$ V $I_{Load} = 1.0$ mA, $V_{DD} = 3.0$ V	V _{OL}		0.4	V
Input High Voltage All Inputs Except RESET RESET	V _{IH}	0.7 x V _{DD} 0.8 x V _{DD}	V _{DD} + 0.3 V _{DD} + 0.3	V V
Input Low Voltage All Inputs	V _{IL}	V _{SS} − 0.3	0.2 x V _{DD}	٧
I/O Ports, Three-State Leakage $PG[7:0]$, PA7, PA3, $PC[7:0]$, $PD[5:0]$, $AS/STRA$, $V_{in} = V_{IH}$ or V_{IL} $MODA/LIR$, $RESET$	loz	_	±10	μΑ
Input Leakage Current (Note 2) Vin = VDD or VSS Vin = VDD or VSS PA[2:0], IRQ, XIRQ MODB/VSTBY	lin		±1 ±10	μ Α μ Α
RAM Standby Voltage Power down	V _{SB}	2.0	V_{DD}	٧
RAM Standby Current Power down	I _{SB}	_	10	μА
Input Capacitance PA[2:0], PE[7:0], IRQ, XIRQ, EXTAL PA7, PA3, PC[7:0], PD[5:0], PG[7:0], AS/STRA, MODA/LIR, RESET	C _{in}	_	8 12	pF pF
Output Load Capacitance All Outputs Except PD[4:1] PD[4:1]	બ	_	90 100	pF pF

Characteristic		Symbol	1 MHz	2 MHz	Unit
Maximum Total Supply Current (Note 3)					
RUN:		lDD			1
Single-Chip Mode	$V_{DD} = 5.5 \text{ V}$		8	15	mA
	$V_{DD} = 3.0 \text{ V}$		4	8	mA
Expanded Multiplexed Mode	$V_{DD} = 5.5 \text{ V}$		14	8 27	m A
	$V_{DD} = 3.0 \text{ V}$		7	14	mA
WAIT: (All Peripheral Functions Shut	Down)	WIDD			l
Single-Chip Mode	$V_{DD} = 5.5 \text{ V}$		3	6	mA
	$V_{DD} = 3.0 \text{ V}$		1.5	6 3	mA
Expanded Multiplexed Mode	$V_{DD} = 5.5 \text{ V}$		5	10	mA
	$V_{DD} = 3.0 \text{ V}$		2.5	10 5	mA
STOP:	100 - 0.0 1	SIDD			
Single-Chip Mode, No Clocks	$V_{DD} = 5.5 \text{ V}$	9,00	50	50	μА
July Chip Mass, via sissile	$V_{DD} = 3.0 \text{ V}$		25	25	μА
Maximum Power Dissipation		PD			
Single-Chip Mode	$V_{DD} = 5.5 \text{ V}$		44	85	mW
,	$V_{DD} = 3.0 \text{ V}$		12	24	mW
Expanded Multiplexed Mode	$V_{DD} = 5.5 \text{ V}$		77	150	mW
•	$V_{DD} = 3.0 \text{ V}$		21	42	mW

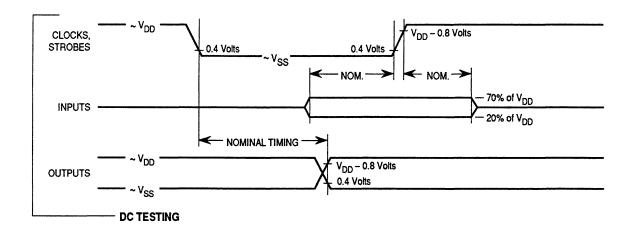
NOTES:

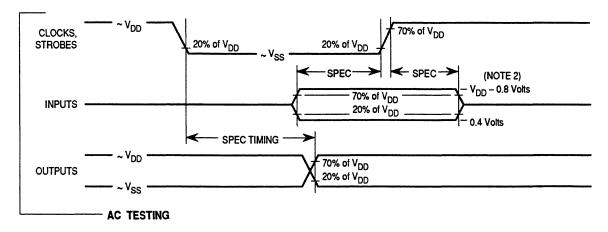
- V_{OH} specification for RESET and MODA is not applicable because they are open-drain pins. V_{OH} specification not applicable to ports C and D in wired-OR mode.
- 2. Refer to A/D specification for leakage current for port E.
- 3. EXTAL is driven with a square wave, and

 t_{cyc} = 1000 ns for 1 MHz rating; t_{cyc} = 500 ns for 2 MHz rating; $V_{IL} \le 0.2 \text{ V}$; $V_{IH} \ge V_{DD} - 0.2 \text{ V}$; No dc loads.

MOTOROLA A-2 SUPPLEMENT TO APPENDIX A ELECTRICAL CHARACTERISTICS







NOTES:

- 1. Full test loads are applied during all DC electrical tests and AC timing measurements.
- 2. During AC timing measurements, inputs are driven to 0.4 volts and V_{DD} 0.8 volts while timing measurements are taken at the 20% and 70% of V_{DD} points.

Figure A-1. Test Methods

MC68L11L6 TECHNICAL DATA SUPPLEMENT TO APPENDIX A ELECTRICAL CHARACTERISTICS

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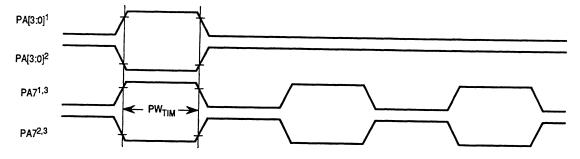
Table A-4a. Control Timing

 V_{DD} = 3.0 Vdc to 5.5 Vdc, V_{SS} = 0 Vdc, T_A = T_L to T_H

Characteristic	Symbol	1.0	MHz	2.0	MHz	Unit
		Min	Max	Min	Max	
Frequency of Operation	fo	dc	1.0	dc	2.0	MHz
E-Clock Period	t _{cyc}	1000	_	500	_	ns
Crystal Frequency	fXTAL	_	4.0		8.0	MHz
External Oscillator Frequency	4 f _o	dc	4.0	dc	8.0	MHz
Processor Control SetupTime tpcSU = 1/4 t _{cyc} + 75 ns	tpcsu	325	_	200	_	ns
Reset Input Pulse Width To Guarantee External Reset Vector Minimum Input Time (Can Be Preempted by Internal Reset)	PWRSTL	8	-	8 1		t _{cyc}
Mode Programming Setup Time	^t MPS	2	_	2		t _{cyc}
Mode Programming Hold Time	tMPH	10	_	10	_	ns
Interrupt Pulse Width, IRQ Edge-Sensitive Mode PW _{IRQ} = t _{cyc} + 20 ns	PWIRQ	1020	_	520	_	ns
Wait Recovery Startup Time	twrs	_	4	_	4	t _{cyc}
Timer Pulse Width, Input Capture Pulse Accumulator Input PW _{TIM} = t _{Cyc} + 20 ns	PW _{TIM}	1020	_	520	_	ns

NOTES:

- RESET is recognized during the first clock cycle it is held low. Internal circuitry then drives the pin low for four clock cycles, releases the pin, and samples the pin level two cycles later to determine the source of the interrupt. Refer to SECTION 5 RESETS AND INTERRUPTS for further detail.
- 2. All timing is shown with respect to 20% V_{DD} and 70% V_{DD} , unless otherwise noted.



NOTES:

- 1. Rising edge sensitive input
- 2. Falling edge sensitive input
- 3. Maximum pulse accumulator clocking rate is E-clock frequency divided by 2.

Figure A-2. Timer Inputs

MOTOROLA A-4 SUPPLEMENT TO APPENDIX A ELECTRICAL CHARACTERISTICS



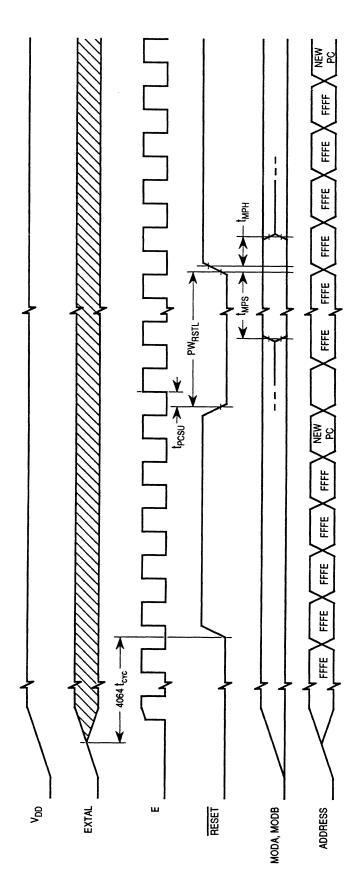


Figure A-3. POR External Reset Timing Diagram

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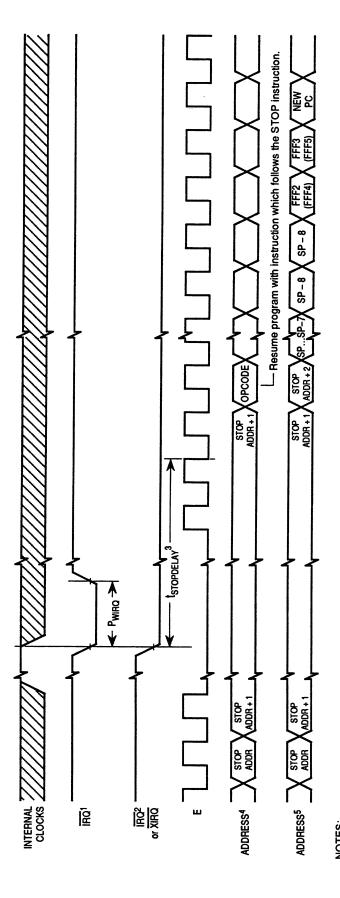


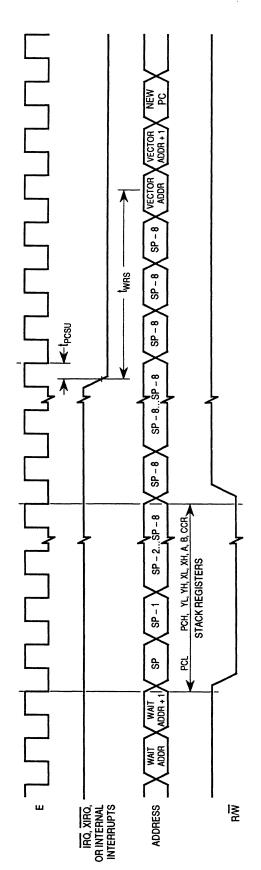
Figure A-4. STOP Recovery Timing Diagram

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MC68L11L6 TECHNICAL DATA

Edge Sensitive IRQ pin (IRQE bit = 1)
 Level sensitive IRQ pin (IRQE bit = 0)
 tstopdelay = 4064 tcyc if DLY bit = 1 or 4 t_{cyc} if DLY = 0.

XIRQ with X bit in CCR = 1.
IRQ or (XIRQ with X bit in CCR = 0).



NOTE: RESET also causes recovery from WAIT.

Figure A-5. WAIT Recovery from Interrupt Timing Diagram

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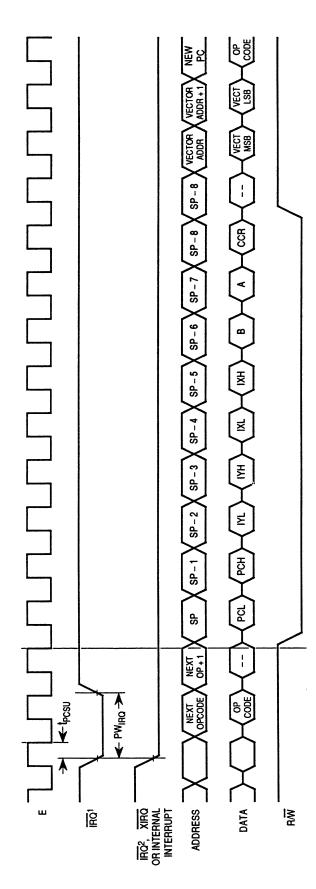


Figure A-6. Interrupt Timing Diagram

NOTES: 1. Edge sensitive \overline{IRQ} pin (IRQE bit = 1) 2. Level sensitive \overline{IRQ} pin (IRQE bit = 0)

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Table A-5a. Peripheral Port Timing

 $V_{DD} = 3.0 \text{ Vdc}$ to 5.5 Vdc, $V_{SS} = 0 \text{ Vdc}$, $T_A = T_L$ to T_H

Characteristic	Symbol	1.0	MHz	2.0	MHz	Unit
		Min	Max	Min	Max	
Frequency of Operation (E-Clock Frequency)	fo	dc	1.0	dc	2.0	MHz
E-Clock Period	t _{cyc}	1000	_	500	_	ns
Peripheral Data Setup Time MCU Read of Ports A, C, D, E, and G	[†] PDSU	100	_	100		ns
Peripheral Data Hold Time MCU Read of Ports A, C, D, E, and G	tPDH	50		50		ns
Delay Time, Peripheral Data Write	tpWD					
MCU Write to Port A MCU Writes to Ports B, C, D, and G $t_{PWD} = 1/4 t_{cyc} + 150 \text{ ns}$		_	250 400	_	250 275	ns ns
Input Data Setup Time (Port C)	tıs	60		60	_	ns
Input Data Hold Time (Port C)	tін	100	_	100	_	ns
Delay Time, E Fall to STRB t _{DEB} = 1/4 t _{cyc} + 150 ns	tDEB		400	_	275	ns
Setup Time, STRA Asserted to E Fall (Note 1)	†AES	0		0		ns
Delay Time, STRA Asserted to Port C Data Output Valid	tPCD	_	100		100	ns
Hold Time, STRA Negated to Port C Data	t _{PCH}	10		10		ns
Three-State Hold Time	tPCZ	_	150	_	150	ns

NOTES:

- If this setup time is met, STRB acknowledges in the next cycle. If it is not met, the response may be delayed one more cycle.
- 2. Port C and D timing is valid for active drive (CWOM and DWOM bits not set in PIOC and SPCR registers respectively).
- 3. All timing is shown with respect to 20% V_{DD} and 70% V_{DD} , unless otherwise noted.

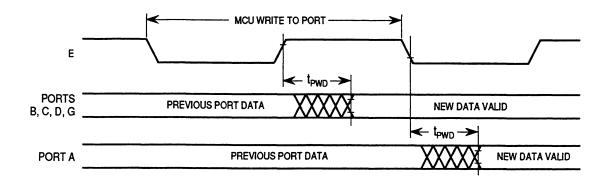


Figure A-7. Port Write Timing Diagram

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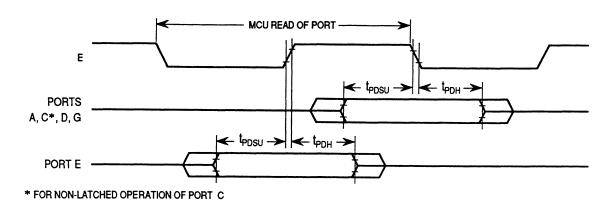


Figure A-8. Port Read Timing Diagram

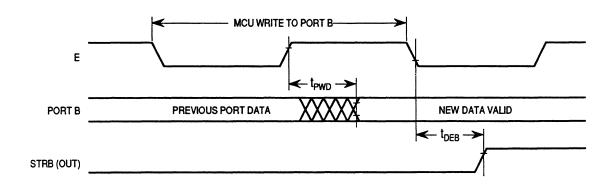


Figure A-9. Simple Output Strobe Timing Diagram

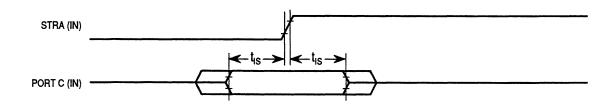
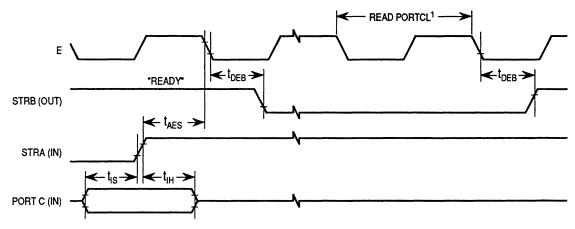


Figure A-10. Simple Input Strobe Timing Diagram

MOTOROLA A-10 SUPPLEMENT TO APPENDIX A ELECTRICAL CHARACTERISTICS

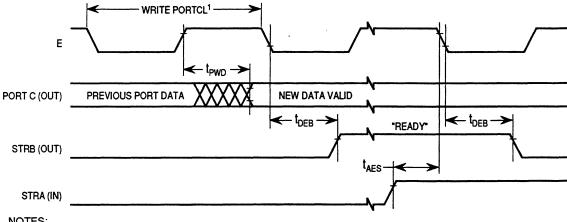




NOTES:

- 1. After reading PIOC with STAF set
- 2. Figure shows rising edge STRA (EGA = 1) and high true STRB (INVB = 1).

Figure A-11. Port C Input Handshake Timing Diagram

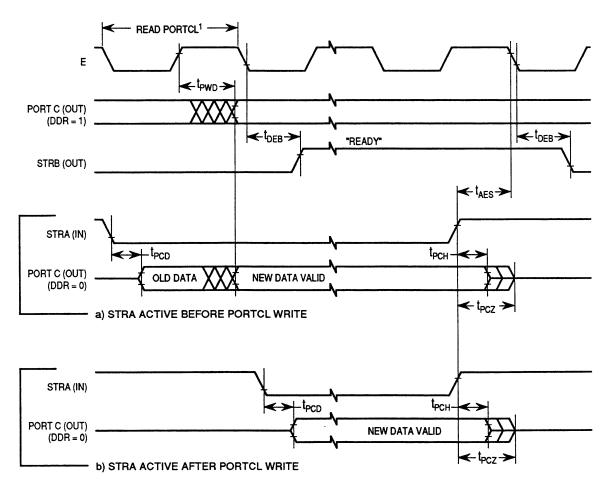


- NOTES:
 - 1. After reading PIOC with STAF set
 - 2. Figure shows rising edge STRA (EGA = 1) and high true STRB (INVB = 1).

Figure A-12. Port C Output Handshake Timing Diagram

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NOTES:

- 1. After reading PIOC with STAF set
- 2. Figure shows rising edge STRA (EGA = 1) and high true STRB (INVB = 1).

Figure A-13. Three-State Variation of Output Handshake Timing Diagram (STRA Enables Output Buffer)



Table A-6a. Analog-To-Digital Converter Characteristics

 $V_{DD} = 3.0 \text{ Vdc}$ to 5.5 Vdc, $V_{SS} = 0 \text{ Vdc}$, $T_A = T_L$ to T_H . 750 kHz $\leq E \leq 2.0 \text{ MHz}$, unless otherwise noted

Characteristic	Parameter	Min	Absolute	Max	Unit
Resolution	Number of Bits Resolved by A/D Converter		8	_	Bits
Non-Linearity	Maximum Deviation from the Ideal A/D Transfer Characteristics		_	±1	LSB
Zero Error	Difference Between the Output of an Ideal and an Actual for Zero Input Voltage		_	±1	LSB
Full Scale Error	Difference Between the Output of an Ideal and an Actual A/D for Full-Scale Input Voltage			±1	LSB
Total Unadjusted Error	Maximum Sum of Non-Linearity, Zero Error, and Full-Scale Error			± 1 1/2	LSB
Quantization Error	Uncertainty Because of Converter Resolution			± 1/2	LSB
Absolute Accuracy	Difference Between the Actual Input Voltage and the Full-Scale Weighted Equivalent of the Binary Output Code, All Error Sources Included		-	±2	LSB
Conversion Range	Analog Input Voltage Range	V_{RL}	_	V _{PH}	٧
V _{RH}	Maximum Analog Reference Voltage	V_{RL}	_	V _{DD} + 0.1	٧
V _{RL}	Minimum Analog Reference Voltage	V _{SS} -0.1	_	V _{PH}	٧
ΔV_{R}	Minimum Difference between V _{RH} and V _{RL}	3.0	_		٧
Conversion Time	Total Time to Perform a Single Analog-to-Digital Conversion:				
	E Clock		32	_	tcyc
	Internal RC Oscillator		_	t _{cyc} + 32	μs
Monotonicity	Conversion Result Never Decreases with an Increase in Input Voltage and has no Missing Codes		Guaranteed		
Zero Input Reading	Conversion Result when V _{in} = V _{RL}	00	_		Hex
Full Scale Reading	Conversion Result when V _{in} = V _{RH}	-	_	FF	Hex
Sample	Analog Input Acquisition Sampling Time:				
Acquisition Time	E Clock		12		t _{cyc}
	Internal RC Oscillator			12	μs
Sample/Hold Capacitance	Input Capacitance During Sample PE[7:0]		20 (Typ)	_	ρF
Input Leakage	Input Leakage on A/D Pins PE[7:0]	-		400	nA
	V _{PL} , V _{PH}	_	_	1.0	μА

NOTES:

1. Source impedances greater than 10 $k\Omega$ affect accuracy adversely because of input leakage.



Table A-7a. Expansion Bus Timing

 $V_{DD} = 3.0 \text{ Vdc}$ to 5.5 Vdc, $V_{SS} = 0 \text{ Vdc}$, $T_A = T_I$ to T_H

Num	Characteristic		Symbol	1.0	MHz	2.0	MHz	Unit
				Min	Max	Min	Max	
	Frequency of Operation (E-Clock Frequency	')	fo	dc	1.0	dc	2.0	MHz
1	Cycle Time		t _{cyc}	1000		500	_	ns
2	Pulse Width, E Low PW _{EL} = 1/2 t _{cyc} – 25 ns		PW _{EL}	475		225		ns
3	Pulse Width, E High PW _{EH} = 1/2 t _{cyc} – 30 ns		PWEH	470	-	220	_	ns
4A 4B	E and AS Rise Time E and AS Fall Time		t _r t _f	_	25 25	_	25 25	ns ns
9	Address Hold Time t _{AH} = 1/8 t _{cyc} - 30 ns	(Note 1a)	^t AH	95	1	33	_	ns
12	Non-Muxed Address Valid Time to E Rise t _{AV} = PW _{EL} - (t _{ASD} + 80 ns)	(Note 1a)	^t AV	275		88		ns
17	Read Data Setup Time		t _{DSR}	30		30		ns
18	Read Data Hold Time (Max = t _{MAD})		t _{DHR}	0	150	0	88	ns
19	Write Data Delay Time t _{DDW} = 1/8 t _{cyc} + 70 ns	(Note 1a)	tDDW		195		133	ns
21	Write Data Hold Time t _{DHW} = 1/8 t _{cyc} - 30 ns	(Note 1a)	^t DHW	95		33		ns
22	Muxed Address Valid Time to E Rise t _{AVM} = PW _{EL} - (t _{ASD} + 90 ns)	(Note 1a)	^t AVM	265		78		ns
24	Muxed Address Valid Time to AS Fall tast = PWash - 70 ns		^t asl	150		25		ns
25	Muxed Address Hold Time t _{AHL} = 1/8 t _{cyc} - 30 ns	(Note 1b)	^t AHL	95		33		ns
26	Delay Time, E to AS Rise t _{ASD} = 1/8 t _{cyc} - 5 ns	(Note 1a)	^t ASD	120		58	_	ns
27	Pulse Width, AS High PW _{ASH} = 1/4 t _{cyc} – 30 ns		PWASH	220		95		ns
28	Delay Time, AS to E Rise t _{ASED} = 1/8 t _{cyc} - 5 ns	(Note 1b)	^t ASED	120		58	_	ns
29	MPU Address Access Time tacca = tcyc - (PWEL-tavm) - tDSR-tf	(Note 1a)	[†] ACCA	735		298	_	ns
35	MPU Access Time tacce = PWEH - tosa		†ACCE	_	440	_	190	ns
36	Muxed Address Delay (Previous Cycle MPU Read) t _{MAD} = t _{ASD} + 30 ns	(Note 1a)	^t MAD	150		88	-	ns

NOTES:

- Input clocks with duty cycles other than 50% affect bus performance. Timing parameters affected by input clock duty cycle are identified by (a) and (b). To recalculate the approximate bus timing values, substitute the following expressions in place of 1/8 t_{cyc} in the above formulas, where applicable:
 - (a) $(1DC) \times 1/4 t_{CVC}$
 - (b) DC \times 1/4 t_{cyc}

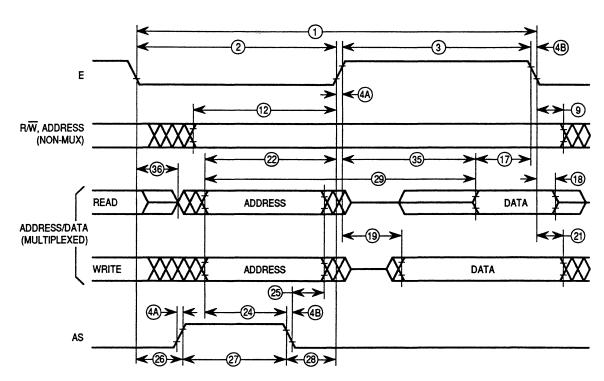
Where:

DC is the decimal value of duty cycle percentage (high time).

2. All timing is shown with respect to 20% V_{DD} and 70% V_{DD} , unless otherwise noted.

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NOTE: Measurement points shown are 20% and 70% of V_{DD} .

Figure A-14. Multiplexed Expansion Bus Timing Diagram



Table A-8a. Serial Peripheral Interface Timing

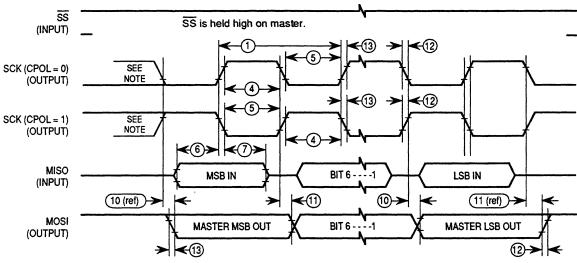
 $V_{DD} = 3.0 \text{ Vdc to } 5.5 \text{ Vdc}, V_{SS} = 0 \text{ Vdc}, T_A = T_L \text{ to } T_H$

Num	Characteristic	Symbol	1.0	MHz	2.0	MHz	Unit
			Min	Max	Min	Max	
	Operating Frequency Master Slave	f _{op(m)} f _{op(s)}	dc dc	0.5 1.0	dc dc	0.5 2.0	f _{op} MHz
1	Cycle Time Master Slave	tcyc(m)	2.0 1000	_	2.0 500		t _{cyc} ns
2	Enable Lead Time Master (Note 2) Slave	tlead(m) tlead(s)	 500	_	 250	_	ns ns
3	Enable Lag Time Master (Note 2) Slave	tlag(m) tlag(s)	 500	=	 250	_	ns ns
4	Clock (SCK) High Time Master Slave	tw(SCKH)m	680 380	=	340 190	_	ns ns
5	Clock (SCK) Low Time Master Slave	tw(SCKL)m tw(SCKL)s	680 380	_	340 190		ns ns
6	Data Setup Time (Inputs) Master Slave	t _{su(m)}	100 100	_	100 100	_	ns ns
7	Data Hold Time (Inputs) Master Slave	th(m) th(s)	100 100	=	100 100	_	ns ns
8	Access Time (Time to Data Active from High-Imp. State) Slave	ta	0	120	0	120	ns
9	Disable Time (Hold Time to High-Impedance State) Slave	^t dis	_	240		240	ns
10	Data Valid (After Enable Edge) (Note 3)	t _{v(s)}	_	240	_	240	ns
11	Data Hold Time (Outputs) (After Enable Edge)	tho	0	_	0	_	ns
12	Rise Time (20% V _{DD} to 70% V _{DD} , C _L = 200 pF) SPI Outputs (SCK, MOSI, and MISO) SPI Inputs (SCK, MOSI, MISO, and SS)	t _{rm}	_	100 2.0	_	100 2.0	ns μs
13	Fall Time (70% V _{DD} to 20% V _{DD} , C _L = 200 pF) SPI Outputs (SCK, MOSI, and MISO) SPI Inputs (SCK, MOSI, MISO, and SS)	t _{fm}		100 2.0	_	100 2.0	ns μs

NOTES:

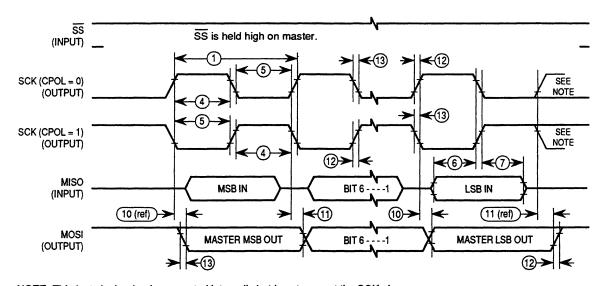
- 1. All timing is shown with respect to 20% V_{DD} and 70% V_{DD} , unless otherwise noted.
- 2. Signal production depends on software.
- 3. Assumes 100 pF load on all SPI pins.





NOTE: This first clock edge is generated internally but is not seen at the SCK pin.

a) SPI Master Timing (CPHA = 0)



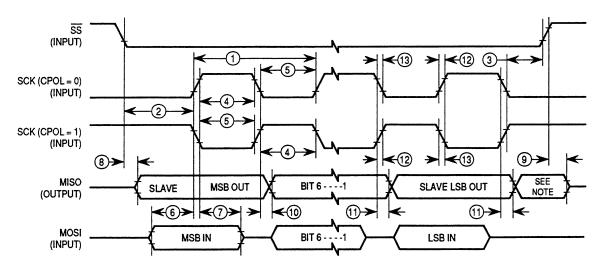
NOTE: This last clock edge is generated internally but is not seen at the SCK pin.

b) SPI Master Timing (CPHA = 1)

Figure A-15. SPI Timing Diagram (1 of 2)

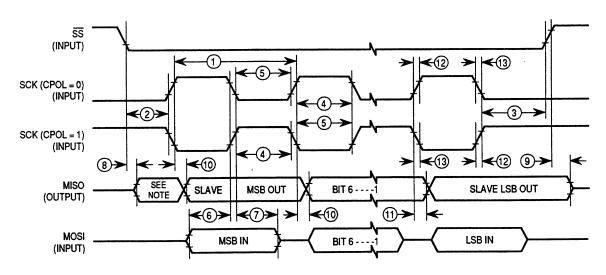
MC68L11L6 TECHNICAL DATA SUPPLEMENT TO APPENDIX A ELECTRICAL CHARACTERISTICS





NOTE: Not defined but normally MSB of character just received.

a) SPI Slave Timing (CPHA = 0)



NOTE: Not defined but normally LSB of character previously transmitted.

b) SPI Slave Timing (CPHA = 1)

Figure A-15. SPI Timing Diagram (2 of 2)

MOTOROLA A-18 SUPPLEMENT TO APPENDIX A ELECTRICAL CHARACTERISTICS



Table A-9a. EEPROM Characteristics

 $V_{DD} = 3.0 \text{ Vdc}$ to 5.5 Vdc, $V_{SS} = 0 \text{ Vdc}$, $T_A = T_L$ to T_H

Charac	(Note 1)5 V, E ≤ 2.0 MHz, RCO Enabledrase Time (Byte, Row and Bulk)3 V, E ≤ 2.0 MHz, RCO Enabled		
Programming Time (Note 1)	3 V, E \leq 2.0 MHz, RCO Enabled 5 V, E \leq 2.0 MHz, RCO Enabled	25 10	ms ms
Erase Time (Byte, Row and Bulk) (Note 1)	3 V, E \leq 2.0 MHz, RCO Enabled 5 V, E \leq 2.0 MHz, RCO Enabled	25 10	ms ms
Write/Erase Endurance (Note 2)		10,000	Cycles
Data Retention (Note 2)		10	Years

NOTES:

- The RC oscillator (RCO) must be enabled (by setting the CSEL bit in the OPTION register) for EEPROM
 programming and erasure.
- 2. Refer to Reliability Monitor Report (current quarterly issue) for current failure rate information.







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